

isc N-Channel MOSFET Transistor

FCPF190N65S3L1

FEATURES

- Drain Current : I_D= 14A@ T_C=25 $^\circ\!\!\!\mathrm{C}$
- Drain Source Voltage
 : V_{DSS}= 650V(Min)
- Static Drain-Source On-Resistance
- : R_{DS(on)} = 0.19 Ω (Max) @ V_{GS}= 10V
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

DESCRIPTION

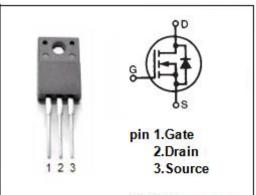
 motor drive, DC-DC converter, power switch and solenoid drive.

• ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

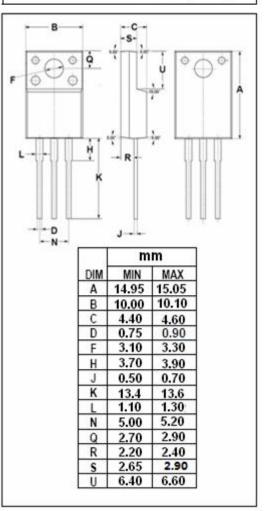
SYMBOL	PARAMETER	VALUE	UNIT
V _{DSS}	Drain-Source Voltage	650	V
V _{GSS}	Gate-Source Voltage	±30	V
ID	Drain Current-Continuous;@Tc=25℃	14	A
I _{DM}	Drain Current-Single Pulsed	35	A
PD	Total Dissipation	33	W
Tj	Operating Junction Temperature	-55~150	°C
T _{stg}	Storage Temperature	-55~150	°C

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
Rth(ch-c)	Channel-to-case thermal resistance	3.76	°C/W



TO-220F package



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ELECTRICAL CHARACTERISTICS

$T_{\text{C}}\text{=}25^{\circ}\!\!\!\!\!\mathrm{C}$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	ТҮР	MAX	UNIT
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V; I _D = 1mA	650			v
$V_{GS(th)}$	Gate Threshold Voltage	V _{DS} =V _{GS} ; I _D = 1.4mA	2.5		4.5	v
R _{DS(on)}	Drain-Source On-Resistance	V _{GS} = 10V; I _D = 7A			0.19	Ω
l _{GSS}	Gate-Source Leakage Current	V _{GS} =±30V;V _{DS} = 0V			±100	nA
I _{DSS}	Drain-Source Leakage Current	V _{DS} = 650V; V _{GS} = 0V			1	uA
Vsd	Diode forward voltage	I _{SD} =7A, V _{GS} = 0 V			1.2	V

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